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TOSHIBA Field Effect Transistor Silicon N Channel MOS Type (π -MOSV)

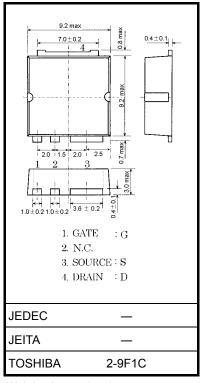
2SK3466

Chopper Regulator Applications

- Low drain-source ON-resistance: R_{DS (ON)} = 1.35 Ω (typ.)
- High forward transfer admittance: $|Y_{fs}| = 4.0 \text{ S}$ (typ.)
- Low leakage current: I_{DSS} = 100 μ A (max) (V_{DS} = 500 V)
- Enhancement mode: V_{th} = 2.0 to 4.0 V (V_{DS} = 10 V, I_D = 1 mA)

Absolute Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit		
Drain-source voltage			V _{DSS}	500	V	
Drain-gate voltage ($R_{GS} = 20 \text{ k}\Omega$)			V _{DGR}	500	V	
Gate-source voltage			V _{GSS}	±30	V	
Drain current	DC	(Note 1)	۱ _D	5	А	
	Pulse	(Note 1)	I _{DP}	20	A	
Drain power dissipation (Tc = 25° C)			PD	50	W	
Single pulse avalanche energy (Note 2)			E _{AS}	180	mJ	
Avalanche current			I _{AR}	5	А	
Repetitive avalanche energy (Note 3)			E _{AR}	5	mJ	
Channel temperature			T _{ch}	150	°C	
Storage temperature range			T _{stg}	-55 to 150	°C	



Weight: 0.74 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Thermal Characteristics

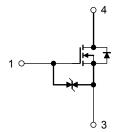
Characteristics	Symbol	Max	Unit
Thermal resistance, channel to case	R _{th (ch-c)}	2.5	°C/W

Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2: V_{DD} = 90 V, T_{ch} = 25°C (initial), L = 12.2 mH, R_G = 25 Ω , I_{AR} = 5 A

Note 3: Repetitive rating: pulse width limited by maximum channel temperature

This transistor is an electrostatic-sensitive device. Handle with care.



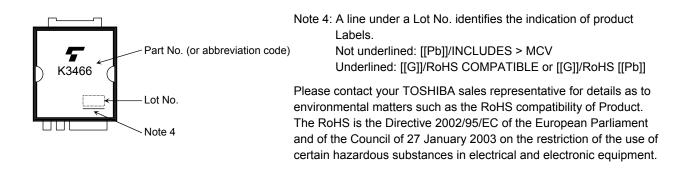
Electrical Characteristics (Ta = 25°C)

Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage cur	e leakage current		$V_{GS}=\pm 25~V,~V_{DS}=0~V$	_		±10	μA
Drain cut-OFF cu	Drain cut-OFF current		$V_{DS} = 500 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$	_		100	μA
Drain-source bre	akdown voltage	V (BR) DSS	$I_D = 10 \text{ mA}, V_{GS} = 0 \text{ V}$	500		_	V
Gate threshold ve	te threshold voltage		$V_{DS} = 10 \text{ V}, \text{ I}_{D} = 1 \text{ mA}$	2.0		4.0	V
Drain-source ON resistance		R _{DS (ON)}	$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 5 \text{ A}$	_	1.35	1.50	Ω
Forward transfer admittance		Y _{fs}	$V_{DS} = 10 \text{ V}, \text{ I}_{D} = 5 \text{ A}$	2.5	4.0		S
Input capacitance		C _{iss}	V _{DS} = 10 V, V _{GS} = 0 V, f = 1 MHz	_	780	_	pF
Reverse transfer capacitance		C _{rss}			60		
Output capacitance		C _{oss}			200		
Switching time	Rise time	tr	$\begin{array}{c} 10 \text{ V} \\ \text{V}_{GS} \\ 0 \text{ V} \\ 15 \Omega \\ \text{M} \\ \text{W}_{DD} \approx 225 \text{ V} \end{array}$		12	_	- ns
	Turn-ON time	t _{on}			25		
	Fall time	t _f			15	_	
	Turn-OFF time	t _{off}		_	60		
Total gate charge (gate-source plus gate-drain)		Qg			17	_	
Gate-source charge		Q _{gs}	$V_{DD} \approx 400 \text{ V}, \text{ V}_{GS} = 10 \text{ V}, \text{ I}_{D} = 5 \text{ A}$	—	11	—	nC
Gate-drain ("miller") charge		Q _{gd}		—	6	—	

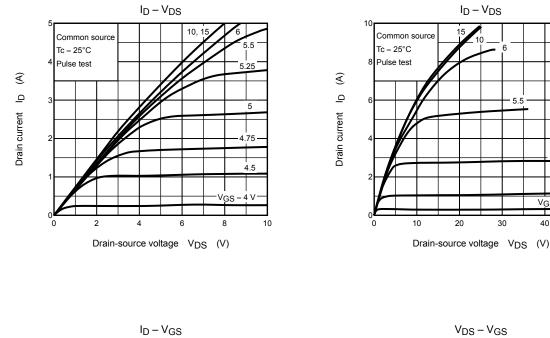
Source-Drain Ratings and Characteristics (Ta = 25°C)

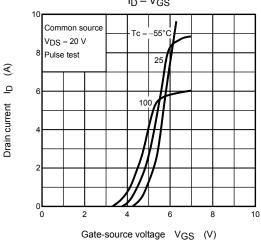
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Continuous drain reverse current (Note 1)	I _{DR}	—	—	_	5	А
Pulse drain reverse current (Note 1)	I _{DRP}	—	_	_	20	А
Forward voltage (diode)	V _{DSF}	I _{DR} = 5 A, V _{GS} = 0 V	_	_	-1.7	V
Reverse recovery time	t _{rr}	$I_{DR} = 5 \text{ A}, V_{GS} = 0 \text{ V},$	_	1400	_	ns
Reverse recovery charge	Q _{rr}	dI _{DR} /dt = 100 A/µs		9		μC

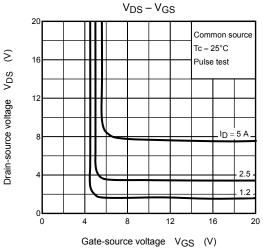
Marking



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5.5

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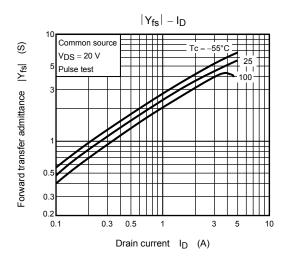
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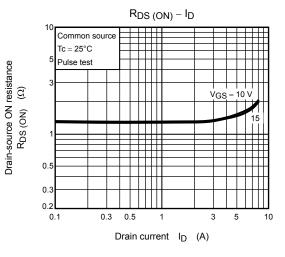
VGS = 4 V

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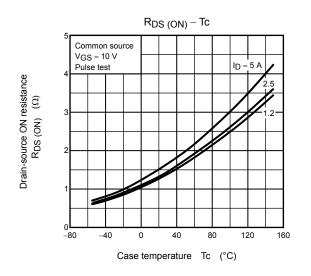
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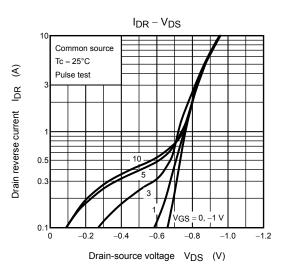
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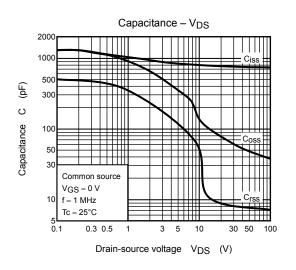


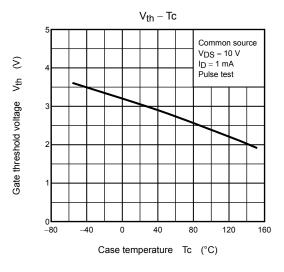


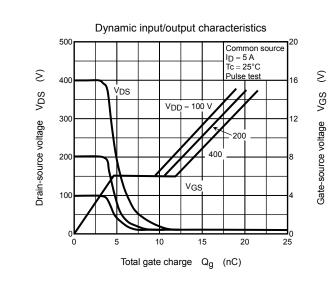
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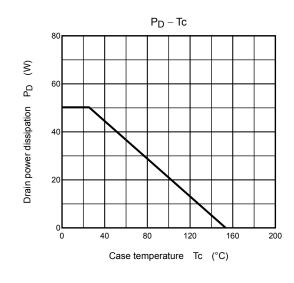


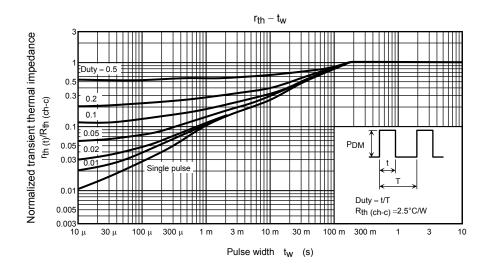




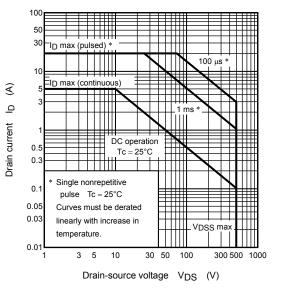


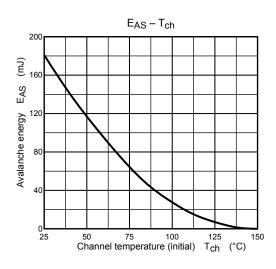


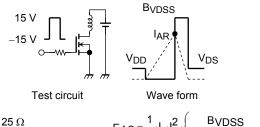




Safe operating area







 $\begin{array}{l} \mathsf{R}_{G} = 25 \ \Omega \\ \mathsf{V}_{DD} = 90 \ \mathsf{V}, \ \mathsf{L} = 12.2 \ \mathsf{mH} \end{array} \qquad \mathsf{E}_{AS} = \frac{1}{2} \cdot \mathsf{L} \cdot \mathsf{I}^{2} \cdot \left(\frac{\mathsf{B}_{VDSS}}{\mathsf{B}_{VDSS} - \mathsf{V}_{DD}} \right)$

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